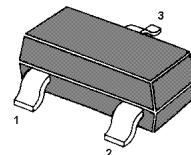




MMUN2114

PNP Silicon Epitaxial Planar Transistor

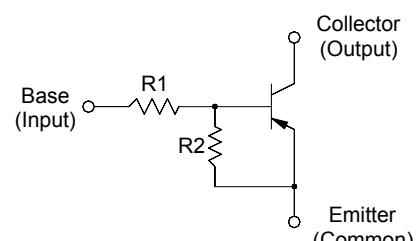
for switching and interface circuit and
drive circuit applications



1.Base 2.Emitter 3.Collector
SOT-23 Plastic Package

Resistor Values

Type	R1 (K)	R2 (K)
MMUN2111	10	10
MMUN2112	22	22
MMUN2113	47	47
MMUN2114	10	47
MMUN2115	10	∞
MMUN2116	4.7	∞
MMUN2130	1	1
MMUN2131	2.2	2.2
MMUN2132	4.7	4.7
MMUN2133	4.7	47
MMUN2134	22	47



Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Collector Base Voltage	$-V_{CBO}$	50	V
Collector Emitter Voltage	$-V_{CEO}$	50	V
Collector Current	$-I_C$	100	mA
Total Power Dissipation	P_{tot}	200	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_s	- 55 to + 150	$^\circ\text{C}$

Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Min.	Max.	Unit
DC Current Gain at $-V_{CE} = 10 \text{ V}$, $-I_C = 5 \text{ mA}$	h_{FE}	35	-	-
	h_{FE}	60	-	-
	h_{FE}	80	-	-
	h_{FE}	80	-	-
	h_{FE}	160	-	-
	h_{FE}	160	-	-
	h_{FE}	3	-	-
	h_{FE}	8	-	-
	h_{FE}	15	-	-
	h_{FE}	80	-	-
Collector Base Cutoff Current at $-V_{CB} = 50 \text{ V}$	$-I_{CBO}$	-	100	nA
Collector Emitter Cutoff Current at $-V_{CE} = 50 \text{ V}$	$-I_{CEO}$	-	500	nA
Emitter Base Cutoff Current at $-V_{EB} = 6 \text{ V}$	$-I_{EBO}$	-	0.5	mA
	$-I_{EBO}$	-	0.2	mA
	$-I_{EBO}$	-	0.1	mA
	$-I_{EBO}$	-	0.2	mA
	$-I_{EBO}$	-	0.9	mA
	$-I_{EBO}$	-	1.9	mA
	$-I_{EBO}$	-	4.3	mA
	$-I_{EBO}$	-	2.3	mA
	$-I_{EBO}$	-	1.5	mA
	$-I_{EBO}$	-	0.18	mA
Collector Base Breakdown Voltage at $-I_C = 10 \mu\text{A}$	$-V_{(BR)CBO}$	50	-	V
Collector Emitter Breakdown Voltage at $-I_C = 2 \text{ mA}$	$-V_{(BR)CEO}$	50	-	V
Collector Emitter Saturation Voltage at $-I_C = 10 \text{ mA}$, $-I_B = 0.3 \text{ mA}$ at $-I_C = 10 \text{ mA}$, $-I_B = 5 \text{ mA}$ at $-I_C = 10 \text{ mA}$, $-I_B = 1 \text{ mA}$	$-V_{CEsat}$	-	0.25	V
	$-V_{CEsat}$	-	0.25	V
	$-V_{CEsat}$	-	0.25	V
	$-V_{CEsat}$	-	0.25	V
	$-V_{CEsat}$	-	0.25	V
	$-V_{CEsat}$	-	0.25	V
	$-V_{CEsat}$	-	0.25	V
	$-V_{CEsat}$	-	0.25	V
	$-V_{CEsat}$	-	0.25	V
	$-V_{CEsat}$	-	0.25	V

**Characteristics at $T_a = 25^\circ\text{C}$**

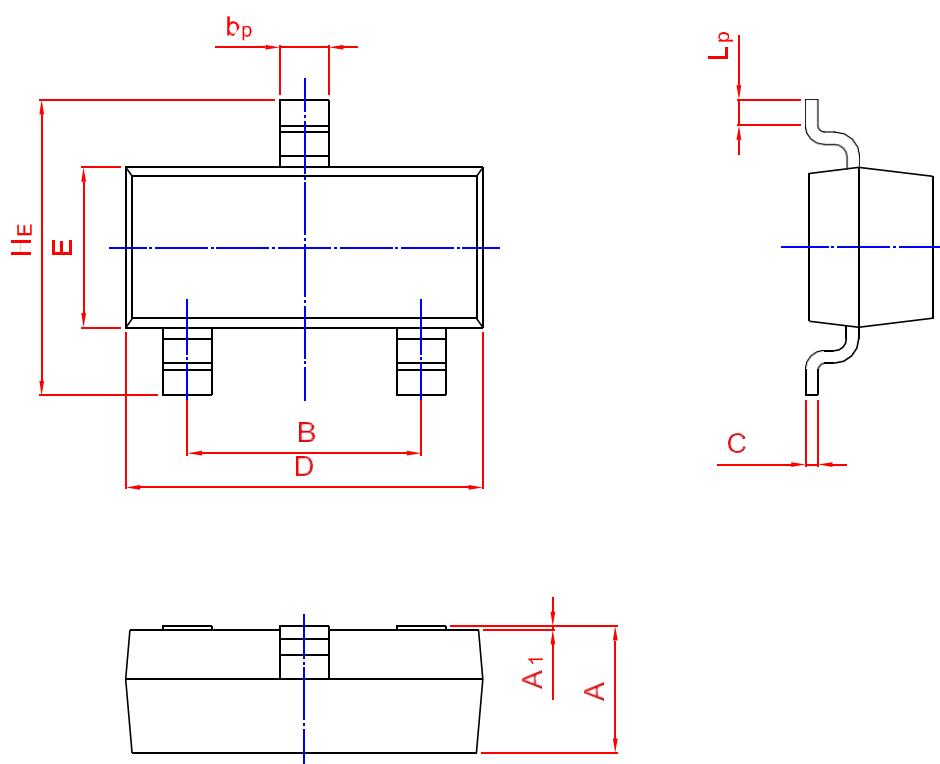
Parameter	Symbol	Min.	Max.	Unit	
Output Voltage (on) at $-V_{CC} = 5 \text{ V}$, $-V_B = 2.5 \text{ V}$, $R_L = 1 \text{ k}\Omega$	MMUN2111 MMUN2112 MMUN2114 MMUN2115 MMUN2116 MMUN2130 MMUN2131 MMUN2132 MMUN2133 MMUN2134 MMUN2113	$-V_{OL}$ $-V_{OL}$ $-V_{OL}$ $-V_{OL}$ $-V_{OL}$ $-V_{OL}$ $-V_{OL}$ $-V_{OL}$ $-V_{OL}$ $-V_{OL}$ $-V_{OL}$	- - - - - - - - - - -	0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2	V V V V V V V V V V
Output Voltage (off) at $-V_{CC} = 5 \text{ V}$, $-V_B = 0.5 \text{ V}$, $R_L = 1 \text{k}\Omega$ at $-V_{CC} = 5 \text{ V}$, $-V_B = 0.05 \text{ V}$, $R_L = 1 \text{k}\Omega$ at $-V_{CC} = 5 \text{ V}$, $-V_B = 0.25 \text{ V}$, $R_L = 1 \text{k}\Omega$	MMUN2130 MMUN2115 MMUN2116 MMUN2131 MMUN2132	$-V_{OH}$ $-V_{OH}$ $-V_{OH}$ $-V_{OH}$ $-V_{OH}$	4.9 4.9 4.9 4.9 4.9	- - - - -	V V V V V
Input Resistor	MMUN2111 MMUN2112 MMUN2113 MMUN2114 MMUN2115 MMUN2116 MMUN2130 MMUN2131 MMUN2132 MMUN2133 MMUN2134	R1 R1 R1 R1 R1 R1 R1 R1 R1 R1 R1	7 15.4 32.9 7 7 3.3 0.7 1.5 3.3 3.3 15.4	13 28.6 61.1 13 13 6.1 1.3 2.9 6.1 6.1 28.6	$\text{k}\Omega$ $\text{k}\Omega$ $\text{k}\Omega$ $\text{k}\Omega$ $\text{k}\Omega$ $\text{k}\Omega$ $\text{k}\Omega$ $\text{k}\Omega$ $\text{k}\Omega$ $\text{k}\Omega$ $\text{k}\Omega$
Resistor Ratio	MMUN2111/MMUN2112/MMUN2113 MMUN2114 MMUN2115/MMUN2116 MMUN2130/MMUN2131/MMUN2132 MMUN2133	R1/R2 R1/R2 R1/R2 R1/R2 R1/R2	0.8 0.17 - 0.8 0.055	1.2 0.25 - 1.2 0.185	- - - - -



PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT-23



UNIT	A	B	b_p	C	D	E	H_E	A_1	L_p
mm	1.40 0.95	2.04 1.78	0.50 0.35	0.19 0.08	3.10 2.70	1.65 1.20	3.00 2.20	0.100 0.013	0.50 0.20